# e2v

# TS83102G0B 10-bit 2 Gsps ADC

# Datasheet

## 1. Features

- Up to 2 Gsps Sampling Rate
- Power Consumption: 4.6 W
- 500 mVpp Differential 100  $\Omega$  or Single-ended 50  $\Omega$  (±2 %) Analog Inputs
- Differential 100  $\Omega$  or Single-ended 50  $\Omega$  Clock Inputs
- ECL or LVDS Output Compatibility
- 50  $\Omega$  Differential Outputs with Common Mode not Dependent on Temperature
- ADC Gain Adjust
- Sampling Delay Adjust
- Offset Control Capability
- Data Ready Output with Asynchronous Reset
- Out-of-range Output Bit
- Selectable Decimation by 32 Functions
- Gray or Binary Selectable Output Data; NRZ Output Mode
- Pattern Generator Output (for Acquisition System Monitoring)
- Radiation Tolerance Oriented Design (More Than 100 Krad (Si) Expected)
- CBGA 152 Cavity Down Hermetic Package
- CBGA Package Evaluation Board TSEV83102G0BGL
- Companion Device: DMUX 8-/10-bit 1:4/1:8 2 Gsps TS81102G0

## 2. Performance

- 3.3 GHz Full Power Input Bandwidth (-3 dB)
- Gain Flatness: ± 0.2 dB (from DC up to 1.5 GHz)
- Low Input VSWR: 1.2 Max from DC to 2.5 GHz
- SFDR = -59 dBc; 7.6 Effective Bits at  $F_S$  = 1.4 Gsps,  $F_{IN}$  = 700 MHz [-1 dBFS]
- SFDR = -53 dBc; 7.1 Effective Bits at Fs = 1.4 Gsps, F<sub>IN</sub> = 1950 MHz [-1 dBFS]
- SFDR = -54 dBc; 6.5 Effective Bits at  $F_S$  = 2 Gsps,  $F_{IN}$  = 2 GHz [-1 dBFS]
- Low Bit Error Rate (10<sup>-12</sup>) at 2 Gsps

## 3. Application

- Direct RF Down Conversion
- Wide Band Satellite Receiver
- High-speed Instrumentation
- High-speed Acquisition Systems
- High-energy Physics
- Automatic Test Equipment
- Radar

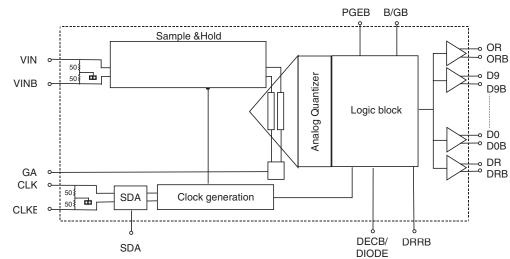
## 4. Screening

- Temperature Range for Packaged Device:
  - "C" grade: 0°C < Tc; Tj < 90°C</p>
  - "V" grade: -20°C < Tc; Tj < 110°C
- Standard Die Flow (upon Request)

## 5. Description

The TS83102G0B is a monolithic 10-bit analog-to-digital converter, designed for digitizing wide bandwidth analog signals at very high sampling rates of up to 2 Gsps. It uses an innovative architecture, including an on-chip Sample and Hold (S/H). The

3.3 GHz full power input bandwidth and band flatness performances enable the digitizing of high IF and large bandwidth signals.



#### Figure 5-1. Simplified Block Diagram

## 6. Functional Description

The TS83102G0B is a 10-bit 2 Gsps ADC. The device includes a front-end master/slave Track and Hold stage (Sample and Hold), followed by an analog encoding stage (Analog Quantizer), which outputs analog residues resulting from analog quantization. Successive banks of latches regenerate the analog residues into logical levels before entering an error correction circuit and resynchronization stage, followed by 50  $\Omega$  differential output buffers.

The TS83102G0B works in a fully differential mode from analog inputs to digital outputs. A differential Data Ready output (DR/DRB) is available to indicate when the outputs are valid and an Asynchronous Data Ready Reset ensures that the first digitized data corresponds to the first acquisition.

The control pin B/GB (A11 of the CBGA package) is provided to select either a binary or gray data output format. The gain control pin GA (R9 of the CBGA package) is provided to adjust the ADC gain transfer function.

A Sampling Delay Adjust function (SDA) may be used to ease the interleaving of ADCs.

A pattern generator is integrated on the chip for debug or acquisition setup. This function is activated through the PGEB pin (A9 of the CBGA package).

An Out-of-range bit (OR/ORB) indicates when the input overrides 0.5 Vpp.

A selectable decimation by 32 functions is also available for enhanced testability coverage (A10 of the CBGA package), along with the die junction temperature monitoring function.

The TS83102G0B uses only vertical isolated NPN transistors together with oxide isolated polysilicon resistors, which allows enhanced radiation tolerance (over 100 kRad (Si) total dose expected tolerance).

## 7. Specification

Parameter	Symbol	Comments	Value	Unit
Positive supply voltage	V <sub>cc</sub>		GND to 6.0	V
Digital negative supply voltage	D <sub>VEE</sub>		GND to -5.7	V
Digital positive supply voltage	V <sub>PLUSD</sub>		GND - 1.1 to 2.5	V
Negative supply voltage	V <sub>EE</sub>		GND to -5.5	V
Maximum difference between negative supply voltages	$D_{VEE}$ to $V_{EE}$		0.3	V
Analog input voltages	V <sub>IN</sub> or V <sub>INB</sub>		-1.5 to 1.5	V
Maximum difference between VIN and VINB	V <sub>IN</sub> - V <sub>INB</sub>		-1.5 to 1.5	V
Clock input voltage	$V_{CLK}$ or $V_{CLKB}$		-1 to 1	V
Maximum difference between VCLK and VCLKB	V <sub>CLK</sub> - V <sub>CLKB</sub>		-1 to 1	Vpp
Static input voltage	V <sub>D</sub>	GA, SDA	-5 to 0.8	V

#### 7.1 Absolute Maximum Ratings

#### 7.1 Absolute Maximum Ratings

Parameter	Symbol	Comments	Value	Unit
Digital input voltage	V <sub>D</sub>	SDAEN, DRRB, B/GB, PGEB, DECB	-5 to 0.8	V
Digital output voltage	Vo		$V_{PLUSD}$ min operating -2.2 to $V_{PLUSD}$ max operating + 0.8	V
Junction temperature	TJ		130	°C

Note: Absolute maximum ratings are short term limiting values (referenced to GND = 0V), to be applied individually, while other parameters are within specified operating conditions. Long exposure to maximum ratings may affect device reliability. All integrated circuits have to be handled with appropriate care to avoid damage due to ESD. Damage caused by inappropriate handling or storage could range from performance degradation to complete failure.

#### 7.2 Recommended Conditions of Use

Parameter	Symbol	Comments	Min	Тур	Max	Unit
Positive supply voltage	V <sub>cc</sub>		4.75	5	5.25	V
		Differential ECL output compatibility	- 0.9	- 0.8	- 0.7	V
Positive digital supply	V <sub>PLUSD</sub>	LVDS output compatibility	1.375	1.45	1.525	V
voltage	12005	(	Grounded <sup>(Not</sup>	e:)		
		Maximum operating VPLUSD			1.7	V
Negative supply voltages	$V_{EE}, D_{VEE}$		- 5.25	- 5.0	- 4.75	V
Differential analog input voltage (full-scale)	V <sub>IN</sub> , V <sub>INB</sub> V <sub>IN</sub> - V <sub>INB</sub>	50 $\Omega$ differential or single-ended	±113 450	±125 500	±137 550	mV mVpp
Clock input power level (ground common mode)	P <sub>CLK</sub> , P <sub>CLKB</sub>	$50 \ \Omega$ single-ended clock input or $100 \ \Omega$ differential clock (recommended)	- 4	0	4	dBm
Operating Temperature Range		Commercial "C" grade Industrial "V" grade	0°C < T <sub>C</sub> ; T <sub>J</sub> < 90°C -20°C < T <sub>C</sub> ; T <sub>J</sub> < 110°C			°C
Storage Temperature	Tstg		-65 to 150		°C	
Lead Temperature	Tlead			300		°C

Note: ADC performances are independent on V<sub>PLUSD</sub> common mode voltage and performances are guaranteed in the limits of the specified V<sub>PLUSD</sub> range (from -0.9V to 1.7V).

## 7.3 Electrical Operating Characteristics

 $V_{CC} = 5V$ ;  $V_{PLUSD} = 0V$  (unless otherwise specified). ADC performances are independent of  $V_{PLUSD}$  common mode voltage and performances are guaranteed within the limits of the specified  $V_{PLUSD}$  range (from -0.9V to 1.7V);  $V_{EE} = D_{VEE} = -5V$ ;  $V_{IN} - V_{INB} = 500$  mVpp (full-scale single-ended or differential input);

clock inputs differential driven; analog-input single-ended driven.

Parameter	Test Level	Symbol	Min	Тур	Max	Unit
Resolution		-		10		Bits
Power Requirements		I I				
Positive supply voltage - analog - digital (ECL) - digital (LVDS)	1 1 4	V <sub>CC</sub> V <sub>PLUSD</sub> V <sub>PLUSD</sub>	4.75	5 - 0.8 1.45	5.25	V V V
Positive supply current - analog - digital	1	I <sub>VCC</sub> I <sub>VPLUSD</sub>		138 154	205 200	mA mA
Negative supply voltage - analog - digital	1	V <sub>EE</sub> D <sub>VEE</sub>	-5.25 -5.25	-5 -5	-4.75 -4.75	V V
Negative supply current - analog - digital Power dissipation	1	V <sub>EE</sub> I <sub>DVEE</sub>		615 160	750 200	mA mA
- ECL - LVDS	1 4	P <sub>D</sub>		4.6 5.0	5.2 5.7	W W
Analog Inputs	1				1	
Full-scale input voltage range (differential mode) (0 V common mode voltage)	4 4	V <sub>IN,</sub> V <sub>INB</sub>	- 125 - 125		125 125	mV mV
Full-scale input voltage range (single-ended input option) (0 V common mode voltage)	4	V <sub>IN,</sub> V <sub>INB</sub>	- 250	0	250	mV mV
Analog input power level (50 $\Omega$ single-ended)	4	P <sub>IN</sub>		- 2		dBm
Analog input capacitance (die)	4	C <sub>IN</sub>		0.3		pF
Input leakage current	4	I <sub>IN</sub>		10		μA
Input resistance - single-ended - differential	4 4	R <sub>IN</sub> R <sub>IN</sub>	49 98	50 100	51 102	Ω Ω
Clock Inputs						
Logic common mode compatibility for clock inputs			Differentia	I ECL to LVDS		

## 7.3 Electrical Operating Characteristics (Continued)

 $V_{CC} = 5V$ ;  $V_{PLUSD} = 0V$  (unless otherwise specified). ADC performances are independent of  $V_{PLUSD}$  common mode voltage and performances are guaranteed within the limits of the specified  $V_{PLUSD}$  range (from -0.9V to 1.7V);  $V_{EE} = D_{VEE} = -5V$ ;  $V_{IN} - V_{INB} = 500$  mVpp (full-scale single-ended or differential input); clock inputs differential driven; analog-input single-ended driven.

Test Parameter Level Symbol Min Max Unit Тур Clock inputs common voltage range (V<sub>CLK</sub> or V<sub>CLKB</sub>) (DC coupled clock input) 0 ٧ 4 V<sub>CM</sub> -1.2 0.3 AC coupled for LVDS compatibility (common mode 1.2V) Clock input power level (low-phase noise sinewave 0 dBm 4 PCIK 4 input) -4 50  $\Omega$  single-ended or 100  $\Omega$  differential Clock input swing (single ended; with CLKB = 50  $\Omega$ 4 ±200 ±320 ±500 mV V<sub>CLK</sub> to GND) Clock input swing (differential voltage) - on each V<sub>CLK</sub> 4 ±141 ±226 ±354 mV clock input V<sub>CLKB</sub> 4 Clock input capacitance (die) CCIK 0.3 pF Clock input resistance 45 - single-ended R<sub>CLK</sub> 50 55 Ω 90 - differential ended 100 R<sub>CLK</sub> 110 Ω Digital Inputs (SDAEN, PGEB, DECB/Diode, B/GB, DRRB) -5 ٧ - logic low VIL -3 4 -2 ٧ - logic high VIH 0 Digital Inputs (DRRB Only) Logic Compatibility Negative ECL - logic low -1.810 -1.625 ٧ VIL 4 VIH -1.165 -0.880 ٧ - logic high Digital Outputs (1) Logic compatibility (depending on V<sub>PLUSD</sub> value) Differential ECL (V<sub>PLUSD</sub> = -0.8V typical) **Output levels** 50  $\Omega$  transmission lines, 100  $\Omega$  (2 x 50  $\Omega$ ) differentially terminated - logic low 1 -1.17 -1.10 ٧ VOL - logic high 1 -0.98 ٧ -0.94 V<sub>OH</sub> - swing (each single-ended output) 200 1 230 300 mV V<sub>OH</sub> - V<sub>OL</sub> - common mode 4 -.095 -1.15 V -1.05 Logic compatibility (depending on V<sub>PLUSD</sub> value) LVDS (V<sub>PLUSD</sub> = 1.45V typical)

## 7.3 Electrical Operating Characteristics (Continued)

 $V_{CC} = 5V$ ;  $V_{PLUSD} = 0V$  (unless otherwise specified). ADC performances are independent of  $V_{PLUSD}$  common mode voltage and performances are guaranteed within the limits of the specified  $V_{PLUSD}$  range (from -0.9V to 1.7V);  $V_{EE} = D_{VEE} = -5V$ ;  $V_{IN} - V_{INB} = 500$  mVpp (full-scale single-ended or differential input); clock inputs differential driven; analog-input single-ended driven.

Parameter	Test Level	Symbol	Min	Тур	Мах	Unit
Output levels 50 $\Omega$ transmission lines, 100 $\Omega$ (2 x 50 $\Omega$ ) differentially terminated						
- logic low	4		825	1090		mV
<ul> <li>logic high</li> <li>swing (each single-ended output)</li> <li>common mode max V<sub>PLUSD</sub> = 1.525V</li> <li> typ V<sub>PLUSD</sub> = 1.45V</li> <li> min V<sub>PLUSD</sub> = 1.375V</li> </ul>	4 4 4 4 4	V <sub>OL</sub> V <sub>OH</sub> V <sub>OH</sub> - V <sub>OL</sub>	200 1190 1125	1310 230 1200	1575 300 1275 1210	mV mV mV mV
DC Accuracy			1125			IIIV
DNLrms <sup>(2)</sup>	4	DNLrms	0.50	0.53	0.55	LSB
Differential non-linearity (3)	1	DNL+		1.5	2	LSB
Integral non-linearity (3)	1	INL-	- 4.0	- 2.4		LSB
Integral non-linearity <sup>(3)</sup>	1	INL+		2.4	4.0	LSB
Gain central value (4)	1		0.89	0.94	1.1	
Gain error drift	4			23	35	ppm/°C
Input offset voltage	1		- 10		10	mV

Note: 1. Differential output buffers impedance = 100  $\Omega$  differential (50  $\Omega$  single-ended). See Figure 13-7 starting on page 42.

2. Histogram testing at Fs = 1 Gsps, Fin = 100 MHz, DNLrms is a component of quantization noise.

3. Histogram testing at Fs = 50 Msps, Fin = 25 MHz

4. This range of gain can be set to "1" by using the gain adjust function.

# 7.4 AC Electrical Characteristics at Ambient and Hot Temperatures (T<sub>J</sub> Max)

Parameter	Test Level	Symbol	Min	Тур	Мах	Unit
AC Analog Inputs						
Full power input bandwidth (Note:)	4	FPBW		3.3		GHz
Small signal input bandwidth (10% full-scale) (Note:)	4	SSBW		3.5		GHz
Gain flatness <sup>(5)</sup>	4	BF		± 0.2	± 0.3	dB
Input voltage standing wave ratio <sup>(6)</sup>	4	VSWR		1.1 :1	1.2:1	
-1 dBFS single-ended input mode (unless otherwise soutput data format	specified); 5	50% clock duty	/ cycle; 0 dBm	differential clo	ck (CLK, CLK	B); binary
Signal-to-noise and distortion ratio			47	50		
Fs = 1 Gsps $Fin = 100 MHz$			44	48		dB
Fs = 1.4 Gsps Fin = 700 MHz	4	SINAD	43	45		
Fs = 1.4 Gsps Fin = 1950 MHz Fs = 2 Gsps Fin = 2 GHz			38	41		
Effective number of bits						
Fs = 1 Gsps Fin = 100 MHz	4	ENOB	7.5	8.0		Bit
Fs = 1.4 Gsps Fin = 700 MHz			7.0	7.6		
Fs = 1.4 Gsps Fin = 1950 MHz			6.8	7.1		
Fs = 2 Gsps Fin = 2 GHz			6.1	6.5		
Signal to noise ratio			40	FO		
Fs = 1 Gsps Fin = 100 MHz	4	SNR	48 45	50		dB
Fs = 1.4 Gsps Fin = 700 MHz			45	48		
Fs = 1.4 Gsps Fin = 1950 MHz			44	45		
Fs = 2 Gsps Fin = 2 GHz			39	41		

				( )	73	,
Parameter	Test Level	Symbol	Min	Тур	Max	Unit
Total harmonic distortion $Fs = 1 Gsps$ Fin = 100 MHz $Fs = 1.4 Gsps$ Fin = 700 MHz $Fs = 1.4 Gsps$ Fin = 1950 MHz $Fs = 2 Gsps$ Fin = 2 GHz	4	ITHDI	48 48 44 44	54 53 50 49		dB
Spurious free dynamic range $Fs = 1 \text{ Gsps}$ Fin = 100 MHz $Fs = 1.4 \text{ Gsps}$ Fin = 700 MHz $Fs = 1.4 \text{ Gsps}$ Fin = 1950 MHz $Fs = 2 \text{ Gsps}$ Fin = 2 GHz	4	ISFDRI	50 50 45 45	59 59 53 54		dBC
Two-tone third-order intermodulation distortion         Fs = 1.2 Gsps         Fin1 = 995 MHz       Fin2 = 1005 MHz [-7dBFS]         Fs = 1.4 Gsps         Fin1 = 745 MHz       Fin2 = 755 MHz [-7dBFS]         Fs = 1.4 Gsps         Fin1 = 995 MHz       Fin2 = 1005 MHz [-7dBFS]         Fs = 1.4 Gsps         Fin1 = 995 MHz       Fin2 = 1005 MHz [-7dBFS]         Fs = 1.4 Gsps         Fin1 = 1244 MHz       Fin2 = 1255 MHz [-7dBFS]	4	IMD31		65 65 65		dBFS

## 7.4 AC Electrical Characteristics at Ambient and Hot Temperatures (T<sub>J</sub> Max) (Continued)

Note: See "Definition of Terms" on page 34.

5. From DC to 1.5 GHz

6. Specified from DC up to 2.5 GHz input signal. Input VSWR is measured on a soldered device. It assumes an external 50  $\Omega$  ±2  $\Omega$  controlled impedance line, and a 50  $\Omega$  driving source impedance (S<sub>11</sub> < - 30 dB).

# 7.5 AC Performance at Cold Temperature (T<sub>C</sub> Min)

		Test					
Parameter		Level	Symbol	Min	Тур	Max	Unit
AC Performance	Condition						
-1 dBFS single-e	nded input mode; 50% clock duty cy	vcle; 0 dBm	differential clo	ock (CLK, CLK	B); binary outpu	ut data format	
Signal-to-noise a	nd distortion ratio			44	10		
Fs = 1 Gsps	Fin = 100 MHz			41	43		dB
Fs = 1.4 Gsps	Fin = 700 MHz	4	SINAD	40 39	42 40		
Fs = 1.4 Gsps	Fin = 1950 MHz			39	40 39		
Fs = 2 Gsps	Fin = 2 GHz			30	39		
Effective number	of bits						
Fs = 1 Gsps	Fin = 100 MHz	4	ENOB	6.5	6.8		Bit
Fs = 1.4 Gsps	Fin = 700 MHz			6.3	6.7		
Fs = 1.4 Gsps	Fin = 1950 MHz			6.2	6.4		
Fs = 2 Gsps	Fin = 2 GHz			6.0	6.2		
Signal to noise ra	atio			45	10		
Fs = 1 Gsps	Fin = 100 MHz	4	SNR	45	46		dB
Fs = 1.4 Gsps	Fin = 700 MHz			44	46 46		
Fs = 1.4 Gsps	Fin = 1950 MHz			45	46 44		
Fs = 2 Gsps	Fin = 2 GHz			43	44		
Total harmonic d	istortion			42	44		
Fs = 1 Gsps	Fin = 100 MHz	4	ITHDI	42			dB
Fs = 1.4 Gsps	Fin = 700 MHz			41	43 42		
Fs = 1.4 Gsps	Fin = 1950 MHz			40 39	42		
Fs = 2 Gsps	Fin = 2 GHz			39	41		
Spurious free dy	namic range			4.4	40		
Fs = 1 Gsps	Fin = 100 MHz			44	46 45		dBC
Fs = 1.4 Gsps	Fin = 700 MHz	4	ISFDRI	43 41	45 43		
Fs = 1.4 Gsps	Fin = 1950 MHz			41	43		
Fs = 2 Gsps	Fin = 2 GHz			41	43		

### 7.6 Transient and Switching Performances

Parameter	Test Level	Symbol	Min	Тур	Мах	Unit
Transient Performance		<u> </u>		l		
Bit error rate (Note:)	4	BER		10 <sup>-12</sup>		Error/ sample
ADC setting time ( $V_{IN}$ - $V_{INB}$ = 400 mVpp)	4	TS		1		ns
Overvoltage recovery time	4	ORT			500	ps
ADC step response rise/fall time (10 - 90%)				80	100	ps
Overshoot				4		%
Ringback				2		%
Switching Performance and Characteristics						
Maximum clock frequency (7)		F <sub>s</sub> Max	2		2.2	Gsps
Minimum clock frequency <sup>(7)</sup>	4	F <sub>s</sub> Min		150	200	Msps
Minimum clock pulse width (high)	4	TC1	0.2	0.25	2.5	ns
Minimum clock pulse width (low)	4	TC2	0.2	0.25	2.5	ns
Aperture delay <sup>(7)</sup>	4	TA		160		ps
Aperture uncertainty <sup>(7)</sup>	4	Jitter		150	200	fs rms
Output rise/fall time for DATA (20 - 80%) (8)	4	TR/TF		150	200	ps
Output rise/fall time for DATA READY (20 - 80%) (8)	4	TR/TF		150	200	ps
Data output delay <sup>(9)</sup>	4	TOD		360		ps
	4	TDR		410		ps
Data ready output delay <sup>(9)</sup>	4	ITOD minus TDRI	0	50	100	ps
Output data to data ready propagation delay (10)	4	TD1	250	300	350	ps
Data ready to output data propagation delay <sup>(10)</sup>	4	TD2	150	200	250	ps
Output data pipeline delay	4	TPD		4.0	·	Clock cycles
Data ready reset delay	4	TRDR	1000			ps

Note: Output error amplitude <  $\pm$ 6 LSB, Fs = 2 Gsps, T<sub>J</sub> = 110°C

- 7. See "Definition of Terms" on page 34.
- 50Ω // C<sub>LOAD</sub> = 2 pF termination (for each single-ended output). Termination load parasitic capacitance derating value: 50 ps/pF (ECL). See "Timing Information" on page 36.
- 9. TOD and TDR propagation times are defined at package input/outputs. They are given for reference only. See "Propagation Time Considerations" on page 36.
- 10. Values for TD1 and TD2 are given for a 2 Gsps external clock frequency (50% duty cycle). For different sampling rates, apply the following formula: TD1 = T/2 + (ITOD TDRI) and TD2 = T/2 + (ITOD TDRI), where T = clock period. This places the rising edge (True/False) of the differential data ready signal in the middle of the output data valid window. This gives maximum setup and hold times for external data acquisition.

Level	Explanation
1	100% production tested at 25°C $^{(1)}$ (for "C" temperature range) $^{(2)}$
2	100% production tested at 25°C <sup>(1)</sup> and sample tested at specified temperatures (for "V" temperature ranges <sup>(2)</sup> )
3	Sample tested only at specified temperatures
4	Parameter is guaranteed by design and characterization testing (thermal steady-state conditions at specified temperature)
5	Parameter is a typical value guaranteed by design only
6	100% production tested over specified temperature range (for "B/Q" temperature range <sup>(2)</sup> )

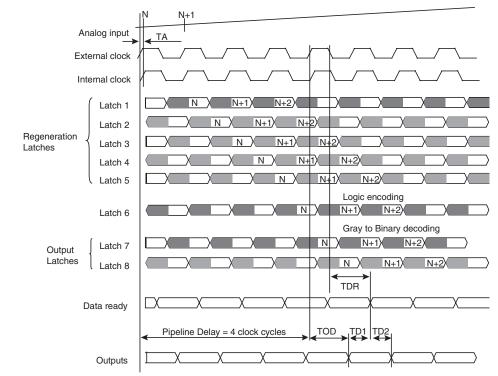
#### Table 7-1. Explanation of Test Levels

Note: 1. Unless otherwise specified

2. Refer to "Ordering Information" on page 55.

Only minimum and maximum values are guaranteed (typical values are issued from characterization results).





Note: Detailed timing diagrams are provided on page 38

#### Table 7-2.Digital Coding

Differential			Digital Output				
Analog Input	Voltage Level	Binary (B/GB = GND MSBLSB Out	•	GRAY (B/GB = V <sub>EE</sub> ) MSBLSB Out-of-Rang			
> 250.25 mV	>Top end of full-scale + ½ LSB	1111111111	1	1000000000	1		
250.25 mV 249.75 mV	Top end of full-scale + ½ LSB Top end of full-scale - ½ LSB	1111111111 1111111110	0 0	1000000000 1000000001	0 0		
125.25 mV 124.75 mV	3/4 full-scale + ½ LSB 3/4 full-scale - ½ LSB	1100000000 1011111111	0 0	1010000000 1110000000	0 0		
0.25 mV -0.25 mV	Mid-scale + ½ LSB Mid-scale - ½ LSB	100000000000000111111111	0 0	1100000000 0100000000	0 0		
-124.75 mV -124.25 mV	1/4 full-scale + ½ LSB 1/4 full-scale - ½ LSB	0100000000	0 0	0110000000	0 0		
-249.75 mV -250.25 mV	Bottom end of full-scale + 1/2 LSB Bottom end of full-scale - 1/2 LSB	0000000001	0 0	0000000001	0 0		
< -250.25 mV	< Bottom end of full-scale - ½ LSB	0000000000	1	0000000000	1		

#### Table 7-3. Die Mechanical Information

Description	Data
Die size	3740 μm x 3820 μm (±15 μm)
Pad size	
- single pad	90 µm x 90 µm
- double pad	180 μm x 90 μm
Die thickness	380 μm ±25 μm
Back side metallization	None
Metallization	
- number of layers	3
- material	AlCu
Pad metallization	AlCu
Passivation	Oxyde nitride
Back side potential	-5V

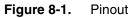
# 8. TS83102G0B Package Description

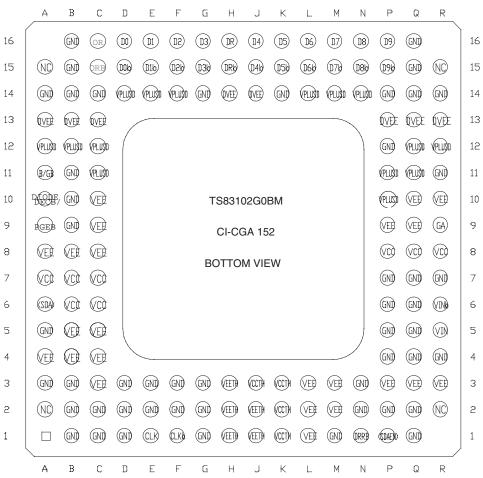
#### **Table 8-1.**Pin Description (CBGA 152)

Symbol	Pin Number	Function
Power Supplies		
V <sub>CC</sub> , V <sub>CCTH</sub>	K1, K2, J3, K3, B6, C6, A7, B7, C7, P8, Q8, R8	5V analog supply (connected to same power supply plane)
GND	B1, C1, D1, G1, M1, Q1, B2, C2, D2, E2, F2, G2, N2, P2, Q2, A3, B3, D3, E3, F3, G3, N3, P4, Q4, R4, A5, P5, Q5, P6, Q6, P7, Q7, R7, B9, B10, B11, R11, P12, A14, B14, C14, G14, K14, P14, Q14, R14, B15, Q15, B16, Q16	Analog ground
$V_{EE}, V_{EETH}$	H1, J1, L1, H2, J2, L2, M2, C3, H3, L3, M3, P3, Q3, R3, A4, B4, C4, B5, C5, A8, B8, C8, C9, P9, Q9, C10, Q10, R10	-5V analog supply (connected to same power supply plane)
V <sub>PLUSD</sub>	P10, C11, P11, Q11, A12, B12, C12, Q12, R12, D14, E14, F14, L14, M14, N14	Digital positive supply
DV <sub>EE</sub>	A13, B13, C13, P13, Q13, R13, H14, J14	-5V digital supply
Analog Inputs		
VIN	R5	In-phase (+) analog input signal of the differential Sample & Hold preamplifier
VINB	R6	Inverted phase (-) analog input signal of the differential Sample & Hold preamplifier
Clock Inputs	•	•
CLK	E1	In-phase (+) clock input
CLKB	F1	Inverted phase (-) clock input
Digital Outputs		
D0, D1, D2, D3, D4, D5, D6, D7, D8, D9	D16, E16, F16, G16, J16, K16, L16, M16, N16, P16	In-phase (+) digital outputs D0 is the LSB, D7 is the MSB
D0B, D1B, D2B, D3B, D4B, D5B, D6B, D7B, D8B, D9B	D15, E15, F15, G15, J15, K15, L15, M15, N15, P15	Inverted phase (-) digital outputs
OR	C16	In-phase (+) out-of-range output
ORB	C15	Inverted phase (-) out-of-range output
DR	H16	In-phase (+) data ready signal output
DRB	H15	Inverted phase (-) data ready signal output
Additional Functions		
B/GB	A11	Binary or gray select output format control - Binary output format if B/GB is floating or connected to GND - Gray output format if B/GB is connected to V <sub>EE</sub>

Symbol	Pin Number	Function
DECB/DIODE	A10	<ul> <li>Decimation function enable or die junction temperature measurement:</li> <li>Decimation active when connected to V<sub>EE</sub> (die junction temperature monitoring is not possible)</li> <li>Normal mode when connected to Ground or left floating</li> <li>Die junction temperature monitoring when current is applied</li> </ul>
PGEB	А9	Active low pattern generator enable - Digitized input delivered at outputs according to B/GB if PGEB is floating or connected to GND - Checker board pattern delivered at outputs if PGEB is connected to V <sub>EE</sub>
DRRB	N1	Asynchronous data ready reset function (active at ECL low level) or when connected to $\rm V_{\rm EE}$
GA	R9	Gain adjust
SDA	A6	Sampling delay adjust
SDAEN	P1	Sampling delay adjust enable - Inactive if floating or connected to GND - Active if connected to V <sub>EE</sub>

#### Table 8-1. Pin Description (CBGA 152) (Continued)





- Note: 1. To simplify PCB routing, the 4 NC balls can be electrically connected to the GND balls.
  - 2. The pinout is shown from the bottom. The columns and rows are defined differently from the JEDEC standard.

## 9. Thermal and Moisture Characteristics

#### 9.1 Dissipation by Conduction and Convection

The thermal resistance from junction to ambient  $RTH_{JA}$  is around 30°C/W. Therefore, to lower  $RTH_{JA}$ , it is mandatory to use an external heat sink to improve dissipation by convection and conduction. The heat sink should be fixed in contact with the top side of the package (CuW heat spreader over Al2O3) which is at -5V.

The heat sink needs to be electrically isolated, using adequate low RTH electrical isolation.

Example:

The thermal resistance from case to ambient  $RTH_{CA}$  is typically 4.0°C/W (0 m/s air flow or still air) with the heat sink depicted in Figure 9-1 on page 18, of dimensions 50 mm x 50 mm x 22 mm (respectively L x I x H).

The global junction to ambient thermal resistance  $RTH_{JA}$  is:

 $4.35^{\circ}$ C/W RTH<sub>JC</sub> + 2.0°C/W thermal grease resistance + 4.0°C/W RTH<sub>CA</sub> (case to ambient) = 10.35°C/W total (RTH<sub>JA</sub>).

Assuming:

A typical thermal resistance from the junction to the bottom of the case  $\text{RTH}_{\text{JC}}$  of  $4.35^{\circ}$ C/W (finite element method thermal simulation results): this value does not include the thermal contact resistance between the package and the external heat sink (glue, paste, or thermal foil interface, for example). As an example, use a 2.0°C/W value for a 50 µm thickness of thermal grease.

Note: Example of the calculation of the ambient temperature  $T_A$  max to ensure  $T_J$  max = 110°C: assuming RTH<sub>JA</sub> = 10.35°C/W and power dissipation = 4.6 W,  $T_A$  max =  $T_J$  - (RTH<sub>JA</sub> x 4.6 W) = 110 - (10.35 x 4.6) = 62.39°C.  $T_A$  max can be increased by lowering RTH<sub>JA</sub> with an adequate air flow (2 m/s, for example).

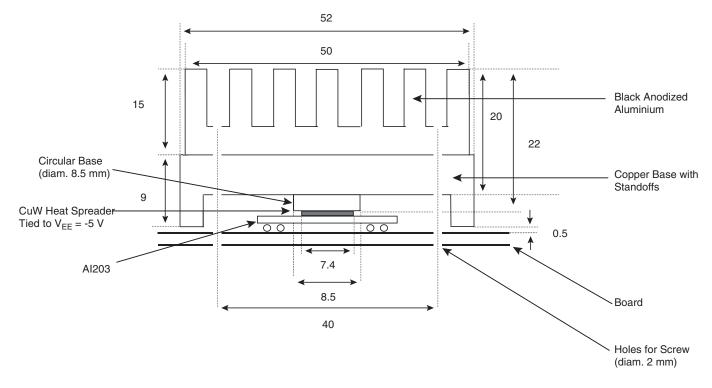


Figure 9-1. Black Anodized Aluminium Heat Sink Glued on a Copper Base Screwed on Board (all dimensions in mm)

Note: The cooling system efficiency can be monitored using the temperature sensing diodes, integrated in the device. Refer to "DECB/DIODE: Junction Temperature Monitoring and Output Decimation Enable" on page 45.

#### 9.2 Thermal Dissipation by Conduction Only

When the external heat sink cannot be used, the relevant thermal resistance is the thermal resistance from the junction to the bottom of the balls: RTH <sub>J-Bottom-of-balls</sub>.

The thermal path, in this case, is the junction, then the silicon, glue, CuW heat spreader, package Al2O3, and the balls (Sn63Pb37).

The Finite Element Method (FEM) with the thermal simulator leads to

 $RTH_{J-bottom of balls} = 12.3^{\circ}C/W$ . This value assumes pure conduction from the junction to the bottom of the balls (this is the worst case, no radiation and no convection is applied). With such an assumption,  $RTH_{J-Bottom-of-balls}$  is user-independent.

To complete the thermal analysis, you must add the thermal resistance from the top of the board (on which the device is soldered) to the ambient resistance, whose values are user-dependent (the type of board, thermal, routing, area covered by copper in each board layer, thickness, airflow or cold plate are all parameters to consider).

## **10. Typical Characterization Results**

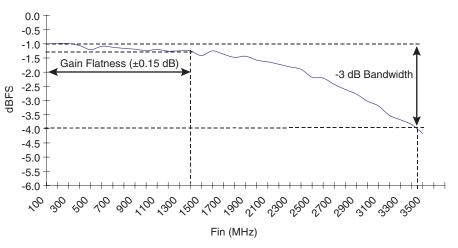
#### **10.1 Nominal Conditions**

 $V_{CC}$  = 5V; 50% clock duty cycle; binary output data format;  $T_J$  = 80°C; -1 dBFS, unless otherwise specified.

#### 10.1.1 Typical Full Power Input Bandwidth

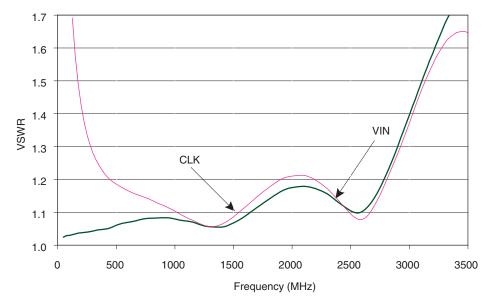
Vin = -1 dBFS Gain flatness at  $\pm 0.15$  dB from DC to 1.5 GHz Full power input bandwidth at -3 dB > 3.3 GHz

Figure 10-1. Full Power Input Bandwidth at -3 dB



#### 10.1.2 Typical VSWR Versus Input Frequency

Figure 10-2. VSWR Curve for VIN and CLK



#### 10.1.3 Typical Step Response

Tr measured = 90 ps = sqrt ( $Tr_{PulseGenerator}^{2}+Tr_{ADC}^{2}$ ) Tr<sub>PulseGenerator</sub> = 41 ps (estimated) Actual Tr<sub>ADC</sub> = 80 ps

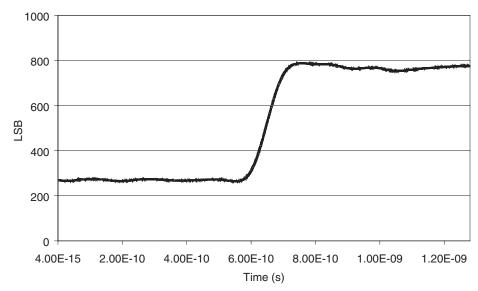
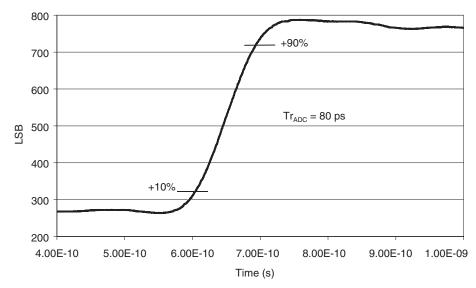


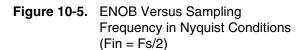
Figure 10-3. Step Response (Random Interleaved Sampling Method Measure)

Figure 10-4. Zoom on Rise Time Step Response



Note: Overshoot and ringback are not measurable (estimated by simulation at 4% and 2% respectively).

#### 10.1.4 Typical Dynamic Performances Versus Sampling Frequency



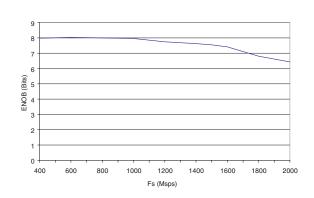
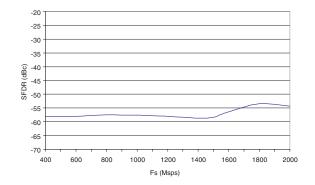
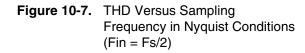


Figure 10-6. SFDR Versus Sampling Frequency in Nyquist Conditions (Fin = Fs/2)





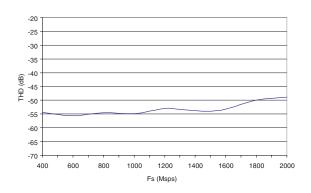
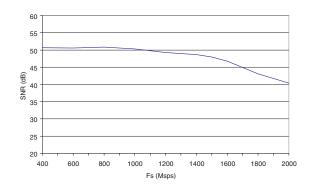
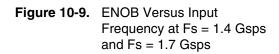
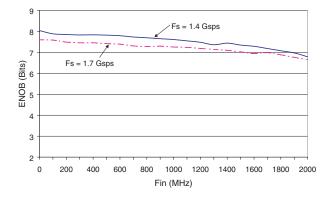


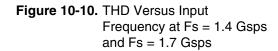
Figure 10-8. SNR Versus Sampling Frequency in Nyquist Conditions (Fin = Fs/2)

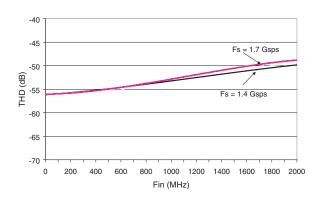


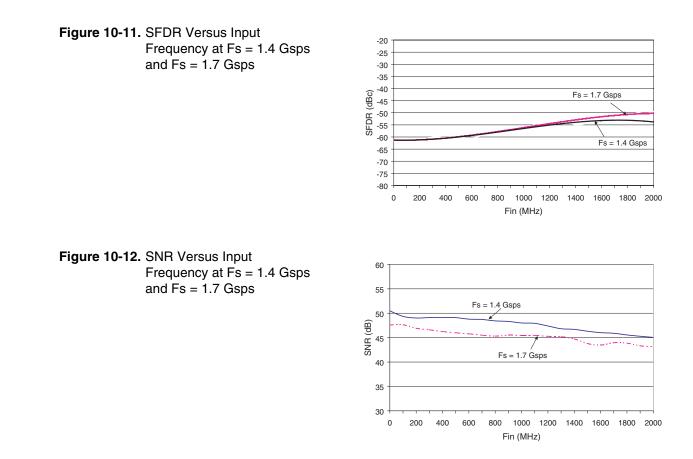
#### 10.1.5 Typical Dynamic Performances Versus Fin











#### 10.1.6 Typical Reconstructed Signals and Signal Spectrum

The ADC input signal is sampled at a full sampling rate, but the output data is 8 or 16 times decimated so as to relax the acquisition system data rate. As a consequence, the calculation software sees an effective frequency divided by 8 or 16, compared to the ADC clock frequency used (Fs). The spectrum is thus displayed from DC to Fs/2 divided by the decimation factor.

Decimation only folds all spectral components between DC and Fs/2 divided by the decimation factor but does not change their amplitude.

This does not have any impact on the FFT spectral characteristics because of the ergodicity of the samples (time average = statistic average). The input frequency is chosen to respect the coherence of the acquisition.

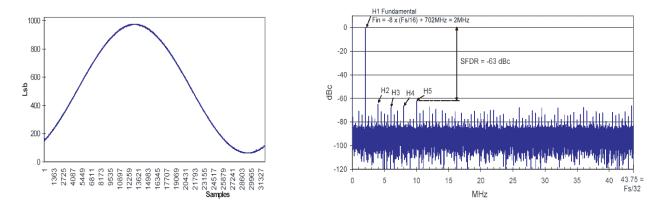


Figure 10-13. Fs = 1.4 Gsps and Fin = 702 MHz, -1 dBFS; Decimation Factor = 16, 32 kpoints FFT

Figure 10-14. Fs = 1.4 Gsps and Fin = 1399 MHz, -1 dBFS; Decimation Factor = 16, 32 kpoints FFT

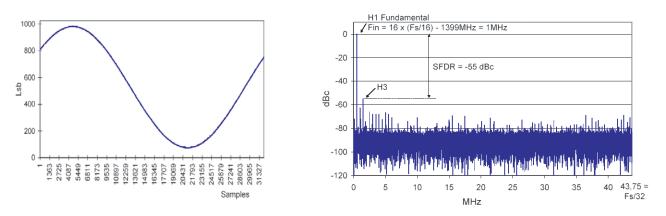
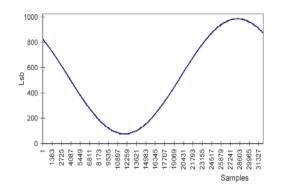
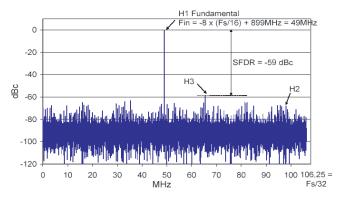
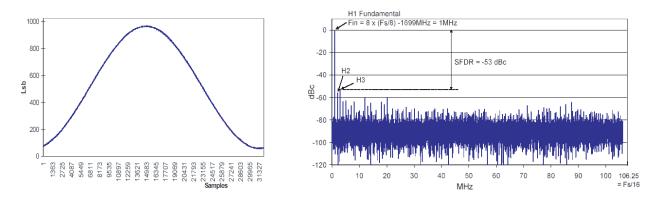


Figure 10-15. Fs = 1.7 Gsps and Fin = 898 MHz, -1 dBFS; Decimation Factor = 16, 32 kpoints FFT

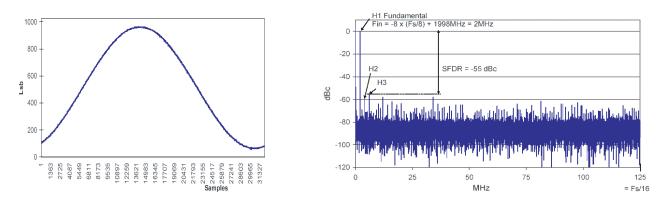




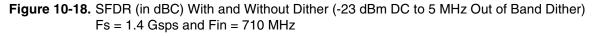


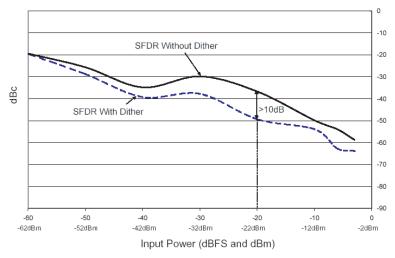
#### Figure 10-16. Fs = 1.7 Gsps and Fin = 1699 MHz, -1 dBFS; Decimation Factor = 8, 32 kpoints FFT

Figure 10-17. Fs = 2 Gsps and Fin = 1998 MHz, -1 dBFS; Decimation Factor = 8, 32 kpoints FFT



#### 10.1.7 SFDR Performance with/without External Dither





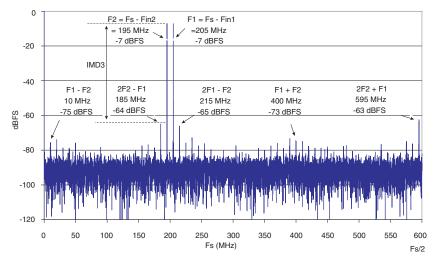
An increase in SFDR up to >10 dB with an addition of -23 dBrms DC to 5 MHz out-of-band dither is noted.

The dither profile has to be defined according to the ADC's INL pattern as well as the trade-off to be reached between the increase in SFDR and the loss in SNR.

Please refer to the Application Note on dither for more information on adding dither to an ADC.

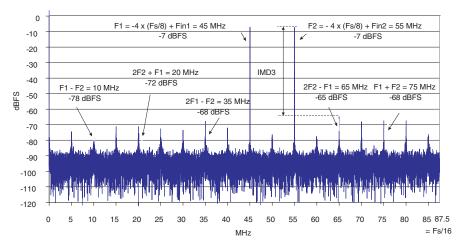
#### 10.1.8 Typical Dual Tone Dynamic Performance

**Figure 10-19.** Dual Tone Reconstructed Signal Spectrum at Fs = 1.2 Gsps, Fin1 = 995 MHz, Fin2 = 1005 MHz (-7 dBFS), IMD3 = 64 dBFS

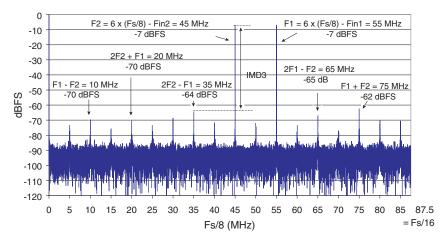


Note: The output data is not decimated. The spectrum is displayed from DC to 600 MHz.

#### **Figure 10-20.** Dual Tone Reconstructed Signal Spectrum at Fs = 1.4 Gsps, Fin1 = 745 MHz, Fin2 = 755 MHz (-7 dBFS), IMD3 = 65 dBFS

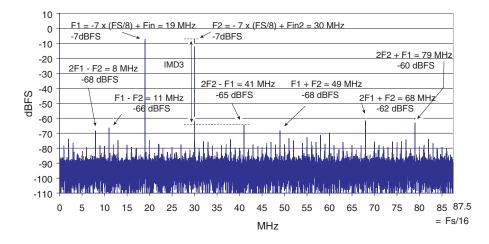


Note: The ADC input signal is sampled at 1.4 Gsps but the data acquisition is 8 times decimated. Thus, the spectrum is displayed from DC to Fs/2 divided by the decimation factor [(Fs/2)/8 = 87.5 MHz].



**Figure 10-21.** Dual Tone Reconstructed Signal Spectrum at Fs = 1.4 Gsps, Fin1 = 995 MHz, Fin2 = 1005 MHz (-7 dBFS), IMD3 = 64 dBFS

- Note: The ADC input signal is sampled at 1.4 Gsps but the data acquisition is 8 times decimated. Thus, the spectrum is displayed from DC to Fs/2 divided by the decimation factor [(Fs/2)/8 = 87.5 MHz].
- **Figure 10-22.** Dual Tone Reconstructed Signal Spectrum at Fs = 1.4 Gsps, Fin1 = 1244 MHz, Fin2 = 1255 MHz (-7 dBFS), IMD3 = 65 dBFS



Note: The ADC input signal is sampled at 1.4 Gsps but data acquisition is 8 times decimated. Thus, the spectrum is displayed from DC to Fs/2 divided by the decimation factor [(Fs/2)/8 = 87.5 MHz]. The dual tone IMD3 at 1.4 Gsps is around -65 dBFS for Fin = 1 GHz  $\pm$  250 MHz (Fin range is from 750 MHz to 1250 MHz).

#### 10.2 Typical Performance Sensitivity Versus Power Supply and Temperature

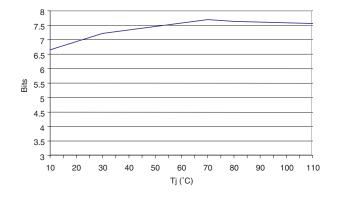


Figure 10-23. ENOB Versus Junction Temperature (Fs = 1.4 Gsps, Fin = 698 MHz, -1 dBFS)

Figure 10-24. SFDR Versus Junction Temperature (Fs = 1.4 Gsps, Fin = 698 MHz, -1 dBFS)

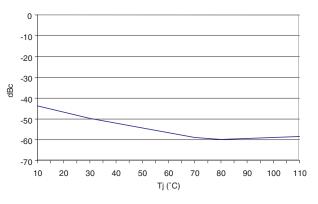
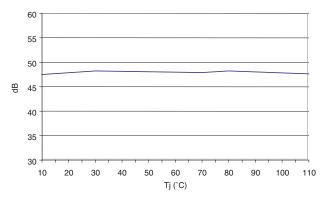


Figure 10-25. SNR Versus Junction Temperature (Fs = 1.4 Gsps, Fin = 698 MHz, -1 dBFS)



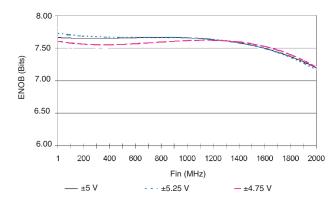
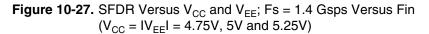


Figure 10-26. ENOB Versus V<sub>CC</sub> and V<sub>EE</sub>; Fs = 1.4 Gsps Versus Fin (V<sub>CC</sub> = IV<sub>EE</sub>I = 4.75V, 5V and 5.25V)



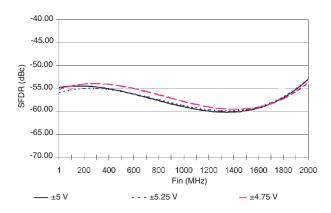
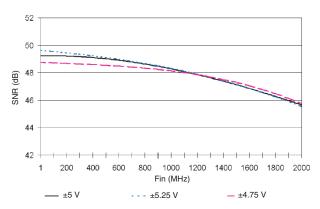
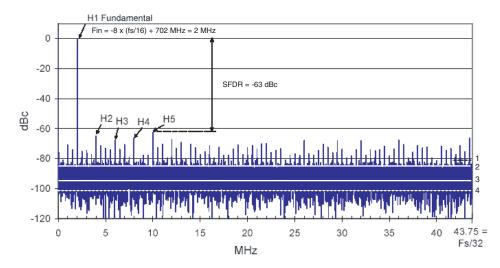


Figure 10-28. SNR Versus V\_{CC} and V\_{EE}; Fs = 1.4 Gsps Versus Fin (V\_{CC} = |V\_{EE}| = 4.75V, 5V and 5.25V)



#### 10.3 Considerations on ENOB: Linearity and Noise Contribution

Figure 10-29. Example of a 16-kpoint FFT Computation at Fs = 1.4 Gsps, Fin = 702 MHz, -1dBFS,  $T_J = 80^{\circ}$ C; Bin Spacing = (Fs/2) / 16384 = 2.67 kHz



This is a 16384 points FFT. It is 16 times decimated since a DEMUX 1:8 is used to relax the acquisition system data rate, and data is captured on the rising edge of the data ready signal.

The spectrum is computed over the first Nyquist zone from DC to Fs/2 divided by the decimation factor, which equals Fs/32 = 43.75 MHz.

Legend:

- 1. Ideal 10-bit quantization noise spectral density, peak value = -84 dB
- 2. Average SNR noise floor: 47 dB + 10 log ( $N_{FFTpoint}/2$ ) = 86 dB including thermal noise
- 3. Average SNR noise floor: 57 dB + 10 log ( $N_{FFTpoint}/2$ ) = 96 dB without thermal noise
- 4. Ideal 10-bit averaged SNR noise floor 6.02 x (N = 10) + 1.76 + 10 log (N<sub>FFTpoint</sub>/2) = 101 dB

Note: The thermal noise floor is expressed in dBm/Hz (at T = 300 K, B = 1 Hz): 10 log (kTB/1 mW) = -174 dBm/Hz or -139.75 dBm/2.67 kHz. THD is calculated over the 25 first harmonics.

With ADC input referred thermal noise:

- ENOB = 7.6 bits
- SINAD = 47 dB
- THD = -55.7 dB (over 25 harmonics)
- SFDR = -62.6 dBc
- SNR = 47.3 dB

Without ADC input referred thermal noise:

- ENOB = 9.2 bits
- SINAD = 57 dB
- THD = -55.7 dB (over 25 harmonics)
- SFDR = -62.6 dBc
- SNR = 57.3 dB

#### Conclusion:

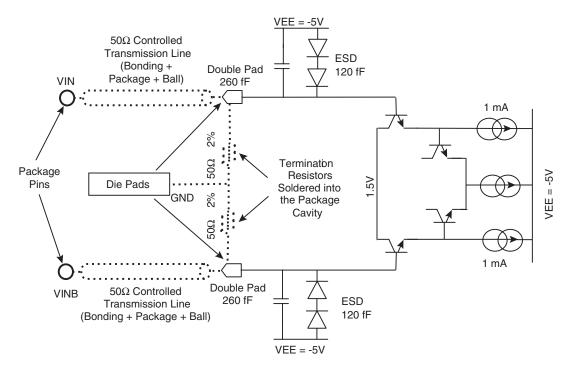
Though the ENOB is 7.6 bits (in this example at 1.4 Gsps Nyquist conditions), the ADC features a 10-bit linearity regarding the 60 dB typical SFDR performance.

However, it has to be pointed out that the ENOB is actually limited by the ADC's input referred thermal noise, which dominates the rms quantization noise. For certain applications (using a spread spectrum) the signal may be recovered below the thermal noise floor (by cross correlation since it is white noise).

Therefore, the thermal noise can be extracted from the ENOB: the ENOB without a referred input thermal noise is 9.2 instead of 7.6 in this example, only limited by the quantization noise and clock induced jitter.

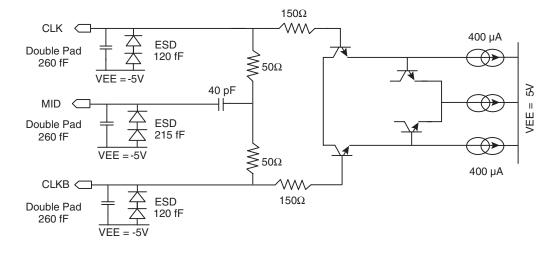
## 11. Equivalent Input/Output Schematics

Figure 11-1. Equivalent Analog Input Circuit and ESD Protections

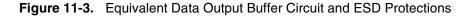


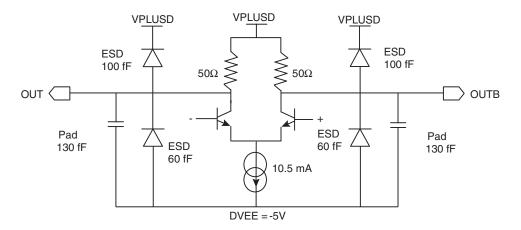
Note: 100  $\Omega$  termination midpoint is located inside the package cavity and is DC coupled to ground.

Figure 11-2. Equivalent Clock Input Circuit and ESD Protections



Note: 100  $\Omega$  termination midpoint is on-chip and AC coupled to ground through a 40 pF capacitor.





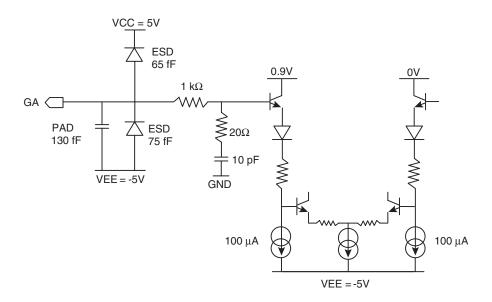
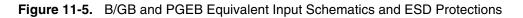
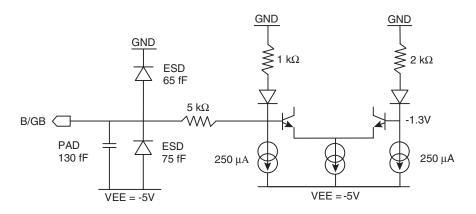
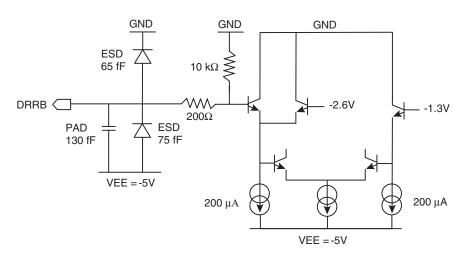


Figure 11-4. ADC Gain Adjust Equivalent Input Circuits and Protections





#### Figure 11-6. DRRB Equivalent Input Schematics and ESD Protections



## 12. Definition of Terms

Term		Description	
BER	Bit Error Rate	Probability to exceed a specified error threshold for a sample. An error code is a code that differs by more than $\pm 4$ LSB from the correct code	
BW	Full-power Input Bandwidth	The analog input frequency at which the fundamental component in the digitally reconstructed output has fallen by 3 dB with respect to its low frequency value (determined by FFT analysis) for input at full-scale	
DG	Differential Gain	The peak gain variation (in percent) at five different DC levels for an AC signal of 20% full-scale peak to peak amplitude. $F_{IN} = 5 \text{ MHz}$ (TBC)	
DNL	Differential Non- linearity	The differential non-linearity for an output code (i) is the difference between the measured step size of code (i) and the ideal LSB step size. DNL (i) is expressed in LSBs. DNL is the maximum value of all DNL (i). DNL error specification of less than 1 LSB guarantees that there are no missing output codes and that the transfer function is monotonic	
DP	Differential Phase	The peak phase variation (in degrees) at five different DC levels for an AC signal of 20% full-scale peak to peak amplitude. $F_{IN} = 5 \text{ MHz} \text{ (TBC)}$	
FS MAX	Maximum Sampling Frequency	Sampling frequency for which ENOB < 6 bits	
FS MIN	Minimum Sampling Frequency	Sampling frequency for which the ADC gain has fallen by 0.5 dB with respect to the gain reference value. Performances are not guaranteed below this frequency	
FPBW	Full Power Input Bandwidth	Analog input frequency at which the fundamental component in the digitally reconstructed output waveform has fallen by 3 dB with respect to its low frequency value (determined by FFT analysis) for input at full-scale -1 dB (-1 dBFS)	
ENOB	Effective Number of Bits	$ENOB = \frac{SINAD - 1,76 + 20\log \frac{A}{F_S/2}}{6,02}$ Where A is the actual input amplitude and V is the full-scale range of the ADC under test	
IMD3	Inter Modulation Distortion	The two tones third order intermodulation distortion (IMD3) rejection is the ratio of either input tone to the worst third order intermodulation products	

#### Table 12-1. Definitions of Terms (Continued)

	Deminicons of Terms (	
INL	Integral Non-linearity	The integral non-linearity for an output code (i) is the difference between the measured input voltage at which the transition occurs and the ideal value of this transition. INL (i) is expressed in LSBs, and is the maximum value of all INL (i)
JITTER	Aperture Uncertainty	The sample to sample variation in aperture delay. The voltage error due to jitter depends on the slew rate of the signal at the sampling point
NPR	Noise Power Ratio	The NPR is measured to characterize the ADC's performance in response to broad bandwidth signals. When using a notch-filtered broadband white-noise generator as the input to the ADC under test, the Noise-to-Power Ratio is defined as the ratio of the average out-of-notch to the average in-notch power spectral density magnitudes for the FFT spectrum of the ADC output sample test
NRZ	Non Return to Zero	When the input signal is larger than the upper bound of the ADC input range, the output code is identical to the maximum code and the out-of-range bit is set to logic one. When the input signal is smaller than the lower bound of the ADC input range, the output code is identical to the minimum code, and the out-of-range bit is set to logic one (it is assumed that the input signal amplitude remains within the absolute maximum ratings)
ORT	Overvoltage Recovery Time	Time to recover 0.2% accuracy at the output, after a 150% full-scale step applied on the input is reduced to midscale
PSRR	Power Supply Rejection Ratio	PSRR is the ratio of input offset variation to a change in power supply voltage
SFDR	Spurious Free Dynamic Range	The ratio expressed in dB of the RMS signal amplitude, set at 1 dB below full-scale, to the RMS value of the next highest spectral component (peak spurious spectral component). SFDR is the key parameter for selecting a converter to be used in a frequency domain application (radar systems, digital receiver, network analyzer). It may be reported in dBc (i.e., degrades as signal level is lowered), or in dBFS (i.e. always related back to converter full-scale)
SINAD	Signal to Noise and Distortion Ratio	The ratio expressed in dB of the RMS signal amplitude, set to 1 dB below full-scale, to the RMS sum of all other spectral components, including the harmonics except DC
SNR	Signal to Noise Ratio	The ratio expressed in dB of the RMS signal amplitude, set to 1 dB below full-scale, to the RMS sum of all other spectral components excluding the first five harmonics
SSBW	Small Signal Input Bandwidth	Analog input frequency at which the fundamental component in the digitally reconstructed output waveform has fallen by 3 dB with respect to its low frequency value (determined by FFT analysis) for input at full-scale -10 dB (-10 dBFS)
TA	Aperture Delay	The delay between the rising edge of the differential clock inputs (CLK,CLKB) (zero crossing point), and the time at which ( $V_{IN}$ , $V_{INB}$ ) is sampled
тс	Encoding Clock Period	TC1 = minimum clock pulse width (high) TC = TC1 + TC2 TC2 = minimum clock pulse width (low)
TD1	Time Delay from Data to Data Ready	General expression is TD1 = TC1 + TDR - TOD with TC = TC1 + TC2 = 1 encoding clock period
TD2	Time Delay from Data Ready to Data	General expression is TD1 = TC1 + TDR - TOD with TC = TC1 + TC2 = 1 encoding clock period
TF	Fall Time	Time delay for the output data signals to fall from 80% to 20% of delta between low level and high level
THD	Total Harmonic Distortion	The ratio expressed in dBc of the RMS sum of the first five harmonic components, to the RMS value of the measured fundamental spectral component
TOD	Digital Data Output Delay	The delay from the falling edge of the differential clock inputs (CLK, CLKB) (zero crossing point) to the next point of change in the differential output data (zero crossing) with a specified load

TPD	Pipeline Delay	The number of clock cycles between the sampling edge of an input data and the associated output data being made available (not taking in account the TOD). For the JTS8388B the TPD is 4 clock periods
TR	Rise Time	Time delay for the output data signals to rise from 20% to 80% of delta between the low level and high level
TRDR	Data Ready Reset Delay	Delay between the falling edge of the Data Ready output asynchronous Reset signal (DDRB) and the reset to digital zero transition of the Data Ready output signal (DR)
TS	Settling Time	Time delay to achieve 0.2% accuracy at the converter output when an 80% full-scale step function is applied to the differential analog input
VSWR	Voltage Standing Wave	$VSWR = (1 + S_{11}) \div (1 - S_{11})$ Where S11 is the reflection coefficient of the scattering matrix. The VSWR over frequency measures the degree of mismatching between the packaged ADC input impedance (ideally 50 $\Omega$ or so) and the transmission line's impedance. The packaged ADC input impedance (transmission line and termination) is controlled so as to ensure VSWR < 1.2 :1 from DC up to 2.5 GHz. A VSWR of 1.2 :1 corresponds to a 0.039 dB insertion loss (20 dB return loss) - i.e. 99% power transmitted and 1% reflected

 Table 12-1.
 Definitions of Terms (Continued)

## 13. TS83102G0B Operating Features

#### **13.1 Timing Information**

#### 13.1.1 Timing Value for TS83102G0B

The timing values are defined in the "Electrical Operating Characteristics" on page 5.

The timing values are given at the package inputs/outputs, taking into account the package's transmission line, bond wire, pad and ESD protections capacitance, as well as specified termination loads. The evaluation board propagation delays in 50  $\Omega$  controlled impedance traces are not taken into account. You should apply proper derating values corresponding to termination topology.

#### 13.1.2 Propagation Time Considerations

The TOD and TDR timing values are given from the package pin to pin and do not include the additional propagation times between the device pins and input/output termination loads. For the evaluation board, the propagation time delay is 6.1 ps/mm (155 ps/inch) corresponding to a 3.4 dielectric constant (at 10 GHz) of the RO4003 used for the board.

If a different dielectric layer is used (for instance Teflon), you should use appropriate propagation time values.

TD1 and TD2 do not depend on propagation times because they are differential data (see "Definition of Terms" on page 34).

TD1 and TD2 are also the most straightforward data to measure, because they are differential: TD can be measured directly on the termination loads, with matching oscilloscope probes.

#### 13.1.3 TOD-TDR Variation Over Temperature

Values for TOD and TDR track each other over the temperature (there is a 1% variation for TOD and TDR per 100°C temperature variation). Therefore the TOD and TDR variation over temperature is negligible. Moreover, the internal (on-chip) skews between each TOD and TDR data effect can be considered

36

negligible. Consequently, the minimum values for TOD and TDR are never more than 100 ps apart. The same is true for their maximum values.

However, the external TOD and TDR values can be dictated by the total digital data skews between each TOD and TDR. These digital skews can include the MCM board, bonding wires and output line length differences, as well as output termination impedance mismatches.

The external (on-board) skew effect has not been taken into account for the specification of TOD and TDR minimum and maximum values.

#### 13.1.4 Principle of Operation

The analog input is sampled on the rising edge of the external clock's input (CLK/CLKB) after TA (aperture delay). The digitized data is available after 4 clock periods' latency (pipeline delay [TPD]) on the clock's rising edge, after a typical propagation delay TOD. The Data Ready differential output signal frequency (DR/DRB) is half the external clock's frequency. It switches at the same rate as the digital outputs. The Data Ready output signal (DR/DRB) switches on the external clock's falling edge after a propagation delay TDR.

If TOD equals TDR, the rising edge (True-False) of the differential Data Ready signal is placed in the middle of the Output Data Valid window. This gives maximum setup and hold times for external data acquisition.

A Master Asynchronous Reset input command DRRB (ECL compatible single-ended input) is available for initializing the differential Data Ready output signal (DR/DRB). This feature is mandatory in certain applications using interleaved ADCs or using a single ADC with demultiplexed outputs. Without Data Ready signal initialization, it is impossible to store the output digital data in a defined order.

When used with e2v's TS81102G0 1:4/8 8/10 bit DMUX, it is not necessary to initialize Data Ready, as this device can start on either clock edge.

## 13.2 Principle of Data Ready Signal Control by DRRB Input Command

#### 13.2.1 Data Ready Output Signal Reset

The Data Ready signal is reset on the DRRB input command's falling edge, on the ECL logical low level (-1.8V). DRRB may also be tied to  $V_{EE} = -5V$  for the Data Ready output signal master reset. As long as DRRB remains at a logical low level, (or tied to  $V_{EE} = -5V$ ), the Data Ready output remains at a logical zero and is independent of the external free-running encoding clock.

The Data Ready output signal (DR/DRB) is reset to a logical zero after TRDR.

TRDR is measured between the -1.3V point of the DRRB input command's falling edge and the zero crossing point of the differential Data Ready output signal (DR/DRB). The Data Ready Reset command may be a pulse of 1 ns minimum time width.

#### 13.2.2 Data Ready Output Signal Restart

The Data Ready output signal restarts on the DRRB command's rising edge, on the ECL logical high level (-0.8V).

DRRB may also be grounded, or may float, for normal free-running of the Data Ready output signal. The Data Ready signal's restart sequence depends on the logical level of the external encoding clock, at a DRRB rising edge instant:

- The DRRB's rising edge occurs when the external encoding clock input (CLK/CLKB) is LOW : the Data Ready output's first rising edge occurs after half a clock period on the clock's falling edge, and a TDR delay time of 410 ps, as defined above.
- The DRRB's rising edge occurs when the external encoding clock input (CLK/CLKB) is HIGH : the Data Ready output's first rising edge occurs after one clock period on the clock's falling edge, and a TDR delay time of 410 ps.

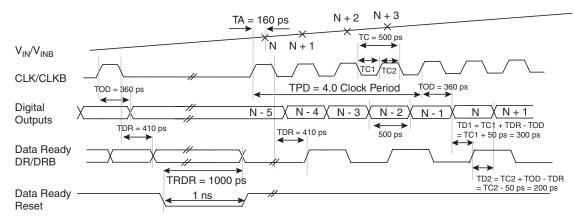
Consequently, as the analog input is sampled on the clock's rising edge, the first digitized data corresponding to the first acquisition (N), after a Data Ready signal restart (rising edge), is always strobed by the third rising edge of the Data Ready signal.

The time delay (TD1) is specified between the last point of a change in the differential output data (zero crossing point) to the rising or falling edge of the differential Data Ready signal (DR/DRB) [zero crossing point].

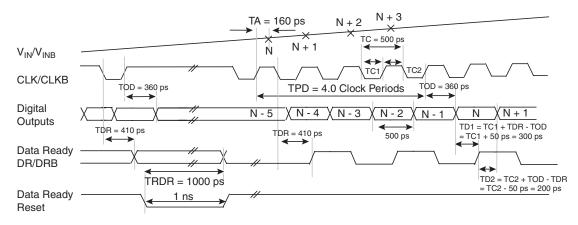
Note: For normal initialization of the Data Ready output signal, the external encoding clock signal frequency and level must be controlled. The minimum encoding clock sampling rate for the ADC is 150 Msps, due to the internal Sample and Hold drop rate. Consequently the clock cannot be stopped.

## 13.2.3 Timing Diagram





## Figure 13-2. TS83102G0B Timing Diagram (2 Gsps Clock Rate) - Data Ready Reset Clock Held at HIGH Level



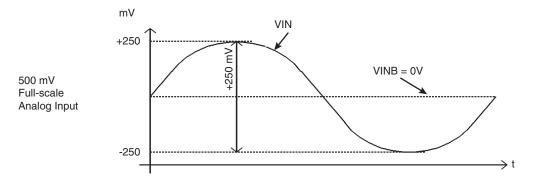
# 13.3 Analog Inputs (VIN/VINB)

#### 13.3.1 Static Issues: Differential Versus Single-ended (Full-scale Inputs)

The ADC's front-end Track and Hold differential preamplifier has been designed to be entered either in differential or single-ended mode, up to the maximum operating speed of 2.2 Gsps, without affecting dynamic performances (it does not require a single to differential balun).

In a single-ended input configuration, the in-phase full-scale input amplitude is 0.5V peak-to-peak, centered on 0V (or -2 dBm into 50  $\Omega$ ).

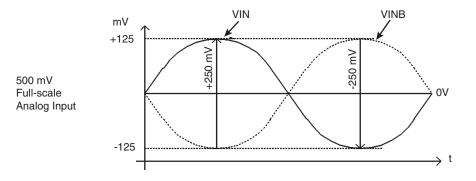
Figure 13-3. Typical Single-ended Analog Input Configuration (Full-scale)



The analog full-scale input range is 0.5V peak-to-peak (Vpp), or -2 dBm into the 50  $\Omega$  (100  $\Omega$  differential) termination resistor.

In the differential mode input configuration, this means 0.25V on each input, or  $\pm 125$  mV around 0V. The input common mode is ground.

Figure 13-4. Differential Inputs Voltage Span (Full-scale)



## 13.3.2 Dynamic Issues:

## Input Impedance and VSWR

The TS83102G0B analog input features a 100  $\Omega$  (±2%) differential input impedance (2 x 50  $\Omega$  // 0.3 pF). Each analog input (VIN,VINB) is terminated by 50  $\Omega$  single-ended (100  $\Omega$  differential) resistors (±2% matching) soldered into the package cavity.

The transmission lines of the ADC package's analog inputs feature a 50  $\Omega$  controlled impedance. Each single-ended die input pad capacitance (taking into account the ESD protection) is

0.3 pF. This leads to a global input VSWR (including ball, package and bounding) of less than 1.2 from DC up to 2.5 GHz.

# 13.4 Clock Inputs (CLK/CLKB)

The TS83102G0B clock inputs are designed for either single-ended or differential operation. The device's clock inputs are on-chip 100  $\Omega$  (2 x 50  $\Omega$ ) differentially terminated. The termination mid point is AC coupled to ground through a 40 pF on-chip capacitor. Therefore, either ground or different common modes can be used (ECL, LVDS).

- Note: As long as V<sub>IH</sub> remains below the 1V peak, the ADC clock can be DC coupled. If V<sub>IH</sub> is higher than the 1V peak, it is necessary to AC couple the signal via 100 pF capacitors, for example, and to bias CLK and CLKB:
  - CLK biased to ground via a 10  $k\Omega$  resistor
  - CLKB biased to ground via a 10 k $\Omega$  resistor and to V\_{EE} via a 100 k $\Omega$  resistor.

However, logic ECL or LVDS square wave clock generators are not recommended because of poor jitter performances. Furthermore, the propagation times of the biasing tees used to offset the common mode voltage to ECL or LVDS levels may not match. A very low-phase noise (low jitter) sinewave input signal should be used for enhanced SNR performance, when digitizing high frequency analog inputs. Typically, when using a sinewave oscillator featuring a

-135 dBc/Hz phase noise, at 20 KHz from the carrier, a global jitter value (including the ADC and the generator) of less than 200 fs RMS has been measured. If the clock signal frequency is at fixed rates, it is recommended to narrow-band filter the signal to improve jitter performance.

Note: The clock input buffer's 100  $\Omega$  termination load is on-chip and mid-point AC coupled (40 pF) to the chip's ground plane, whereas the analog input buffer's 100  $\Omega$  termination is soldered inside the package cavity and mid-point DC coupled to the package ground plane. Therefore, driving the analog input in single-ended mode does not perturb the chip's ground plane (since the termination mid-point is connected to the package ground plane). However, driving the clock input in single-ended mode does perturb the chip's ground plane (since the termination mid-point is AC coupled to the chip's ground plane). Therefore, it is required to drive the clock input in differential mode for minimum chip ground plane perturbation (a 4 dBm maximum operation is recommended). The typical clock input power is 0 dBm. The minimum operating clock input power is -4 dBm (equivalent to a 250 mV minimum swing amplitude), to avoid SNR performance degradations linked to the clock signal's slew rate.

A single to differential balun with sqrt (2) ratio may be used (featuring a 50  $\Omega$  input impedance with 100  $\Omega$  differential termination).

For instance:

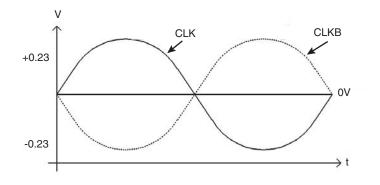
4 dBm is equivalent to 1 Vpp into 50  $\Omega$  and 1.4 Vpp into 100  $\Omega$  termination (secondary). 0 dBm is equivalent to 0.632 Vpp into 50  $\Omega$  and 0.632 x sqrt (2) = 0.894 Vpp into 100  $\Omega$  termination (secondary), ± 0.226V at each clock input.

The recommended clock input's common mode is ground.

40

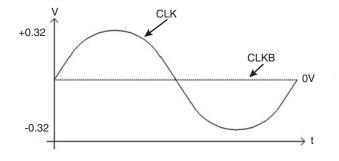
## 13.4.1 Differential Clock Inputs Voltage Levels (0 dBm Typical)

Figure 13-5. Differential Clock Inputs - Ground Common Mode (Recommended)



#### 13.4.2 Equivalent Single-ended Clock Input Voltage Levels (0 dBm Typical)

Figure 13-6. Single-ended Clock Inputs - Ground Common Mode



## 13.5 Noise Immunity Information

The circuit's noise immunity performance begins at the design level. Efforts have been made on the design to make the device as insensitive as possible to chip environment perturbations, which may result from the circuit itself or be induced by external circuitry (cascode stage's isolation, internal damping resistors, clamps, internal on-chip decoupling capacitors.)

Furthermore, the fully differential operation from the analog input up to the digital output provides enhanced noise immunity by common mode noise rejection. The common mode noise voltage induced on the differential analog and clock inputs is cancelled out by these balanced differential amplifiers.

Moreover, proper active signal shielding has been provided on the chip to reduce the amount of coupled noise on the active inputs. The analog and clock inputs of the TS83102G0B device have been surrounded by ground pins, which must be directly connected to the external ground plane.

# 13.6 Digital Outputs: Termination and Logic Compatibility

Each single-ended output of the TS83102G0B's differential output buffers are internally 50  $\Omega$  terminated, and feature a 100  $\Omega$  differential output impedance. The 50  $\Omega$  resistors are connected to the VPLUSD digital power supply. The TS83102G0B output buffers are designed to drive 50  $\Omega$  controlled impedance lines properly terminated by a 50  $\Omega$  resistor. A 10.5 mA bias current flowing alternately into one of the 50  $\Omega$  resistors when switching, ensures a 0.25V

single-ended voltage drop across the resistor (0.5V differential).

Each single-ended output transmission line length must be kept identical (< 3 mm). Mismatches in the differential line lengths may cause variations in the output differential common mode.

It is recommended to bypass the midpoint of the differential 100  $\Omega$  termination with a 47 pF capacitor, so as to avoid common mode perturbations in case of a slight mismatch in the differential output line lengths.

See the recommended termination scenarios in Figures 46. and 47. below.

Note: Since the output buffers feature a 100  $\Omega$  differential output impedance, it is possible to directly drive high the input impedance storing registers without terminating the 50  $\Omega$  transmission lines. Timewise, this means that the incident wave reflects at the 50  $\Omega$  transmission line output and travels back to the 50  $\Omega$  data output buffer. Since the buffer output impedance is 50  $\Omega$ , no back reflection occurs and the output swing is doubled.

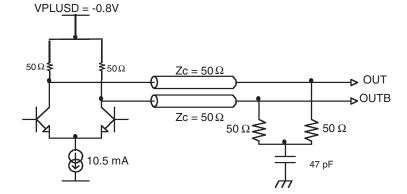
#### 13.6.0.1 VPLUSD Digital Power Supply Settings

- For differential ECL digital output levels: V<sub>PLUSD</sub> should be supplied with -0.8V (or connected to ground via a 5 Ω resistor to ensure the -0.8 voltage drop).
- For the LVDS digital output logic compatibility: V<sub>PLUSD</sub> should be tied to 1.45V (±75 mV).

If used with the TS81102G0 DMUX,  $V_{PLUSD}$  can be set to ground.

## 13.6.1 ECL Differential Output Termination Configurations





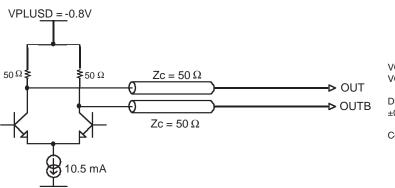
VOL typ = -1.17V VOH typ = -0.94V

Differential Output Swing: ±0.23V = 0.46 Vpp

Common Mode Level = -1.05V

42





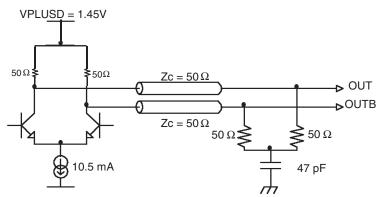
VOL typ = -1.4V VOH typ = -0.94V

Differential Output Swing: ±0.46V = 0.92 Vpp

Common Mode Level = -1.17V

## 13.6.2 LVDS Differential Output Loading Configurations



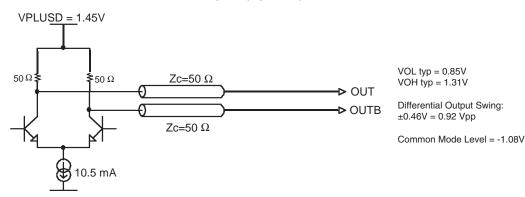


VOL typ = 1.09V VOH typ = 1.31V

Differential Output Swing:  $\pm 0.23$  Vp = 0.46 Vpp

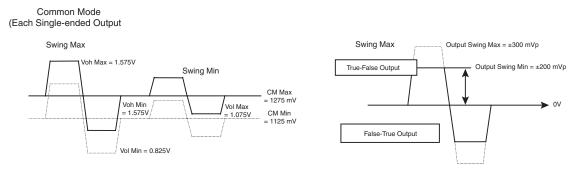
Common Mode Level = 1.20V

## Figure 13-10. Unterminated Differential Outputs (Optional)



## 13.6.3 LVDS Logic Compatibility

Figure 13-11. LVDS Format (Refer to the IEEE Standards 1596.3 - 1994): 1125 mV < Common Mode <1275 mV and 250 mV < Output Swing < 400 mV



# 13.7 Main Functions of the ADC

## 13.7.1 Out-of-range Bit (OR/ORB)

The out-of-range bit reaches a logical high state when the input exceeds the positive full-scale or falls below the negative full-scale. When the analog input exceeds the positive full-scale, the digital outputs remain at a logical high state with OR/ORB at a logical one. When the analog input falls below the negative full-scale, the digital outputs remain at a logical low state, with OR/ORB at a logical one again.

## 13.7.2 Bit Error Rate (BER)

The TS83102G0B's internal regeneration latches indecisions (for inputs very close to the latches' threshold). This may produce errors in the logic encoding circuitry, leading to large amplitude output errors.

This is because the latches regenerate the internal analog residues into logical states with a finite voltage gain value (Av) within a given positive amount of time D(t): Av = exp (D (t)/t), with t being the positive regeneration time constant feedback.

The TS83102G0B has been designed to reduce the probability of such errors occuring to 10-12 (measured for the converter at 2 Gsps). A standard technique for reducing the amplitude of such errors down to  $\pm 1$  LSB consists in setting the digital output data to gray code format. However, the TS83102G0B has been designed to feature a Bit Error Rate of 10-12 with a binary output format.

## 13.7.3 Gray or Binary Output Data Format Selection

To reduce the amplitude of such errors when they occur, it is possible to choose between the binary or gray output data format by storing gray output codes.

Digital data format selection:

- BINARY output format if B/GB is floating or GND.
- GRAY output format if B/GB is connected to V<sub>EE</sub>.

## 13.7.4 Pattern Generator Function

The pattern generator function (enabled by connecting pin A9 PGEB to  $V_{EE} = -5V$ ) allows you to rapidly check the ADC's operation thanks to a checker board pattern delivered internally to the ADC. Each of

the ADC's output bits should toggle from 0 to 1 successively, giving sequences such as 0101010101 and 1010101010 every 2 cycles. This function is disabled when PGEB is left floating or connected to Ground.

#### 13.7.5 DECB/DIODE: Junction Temperature Monitoring and Output Decimation Enable

The DECB/DIODE pin is provided to enable the decimation function and monitor the die junction temperature.

When  $V_{EE} = -5V$ , the ADC runs in "decimation by 32" mode (1 out of 32 data is output from the ADC, thus reducing the data rate by 32).

When the DECB/DIODE pin is left floating or connected to Ground, then the ADC is said to be in a "normal" mode of operation (the output data is not decimated) and can be used for die junction temperature monitoring only.

If you do not intend to use the die junction temperature monitoring function, the DECB/DIODE pin (A10) has to be left either floating or connected to ground.

The decimation function can be used to debug the ADC at initial stages. This function enables you to reduce the ADC output rate by 32, thus reducing the time of the ADC's debug phase at the maximum speed rate, and is compatible with industrial testing environments.

When this function is active, the ADC outputs only 1 out of 32 bits of data, resulting in a data rate 32 times slower than the clock rate.

Note: The ADC decimation test mode is different from the pattern generator function, which is used to check the ADC's outputs.

#### 13.7.6 External Configuration Description

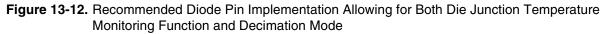
Because of the use of one internal diode-mounted transistor (used for junction temperature monitoring), you have to implement external head-to-tail protection diodes so as to avoid potential reverse current flows, which can damage the internal diode component.

Two external configurations are possible:

- Configuration 1: allows both junction temperature monitoring and output data decimation.
- Configuration 2: allows junction temperature monitoring only.

#### 13.7.6.1 Configuration 1

This external configuration allows you to apply the requested levels to activate output data decimation  $(V_{EE} = -5V)$  and at the same time monitor the junction temperature diode (this explains why 7 protection diodes are needed in the other direction, as shown in Figure 51).



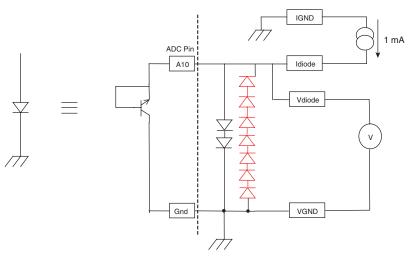
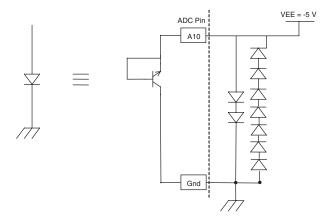


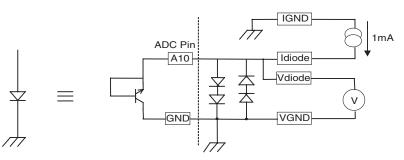
Figure 13-13. Diode Pin Implementation for Decimation Activation



## 13.7.6.2 Configuration 2:

Note: In the preliminary specification, e2v recommends the use of 2 x 3 head-to-tail protection diodes.

Figure 13-14. Diode Pin Implementation of Die Junction Temperature Monitoring Function Only



#### 13.7.7 Junction Temperature Diode Transfer Function

The forward voltage drop ( $V_{DIODE}$ ), across the diode component, versus the junction temperature (including the chip's parasitic resistance) is given in the following graph ( $I_{DIODE} = 1 \text{ mA}$ ).

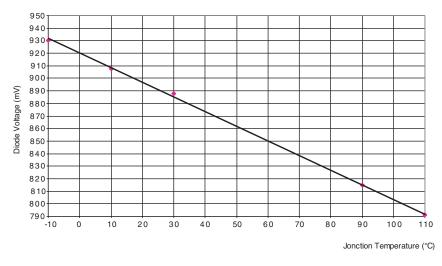


Figure 13-15. Junction Temperature Versus Diode Voltage for I = 1 mA

#### 13.7.8 ADC Gain Control

The ADC gain is adjustable by using pin R9 of the CBGA package. The gain adjust transfer function is shown below.

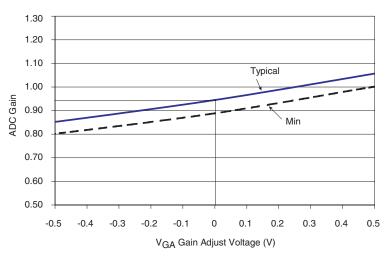


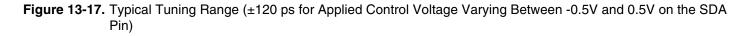
Figure 13-16. Gain Adjust Transfer Function

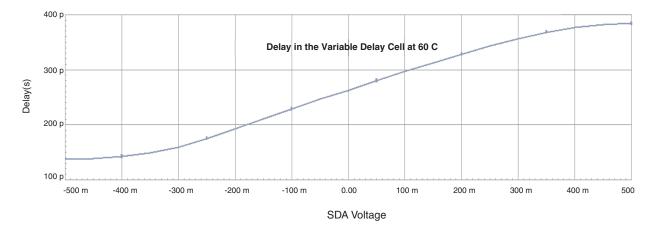
#### 13.7.9 Sampling Delay Adjust

The sampling delay adjust (SDA pin) enables you to fine-tune the sampling ADC aperture delay TAD around its nominal value (160 ps). This functionality is enabled with the SDAEN signal, which is active when tied to  $V_{EE}$  and inactive when tied to GND.

This feature is particularly interesting for interleaving ADCs to increase the sampling rate.

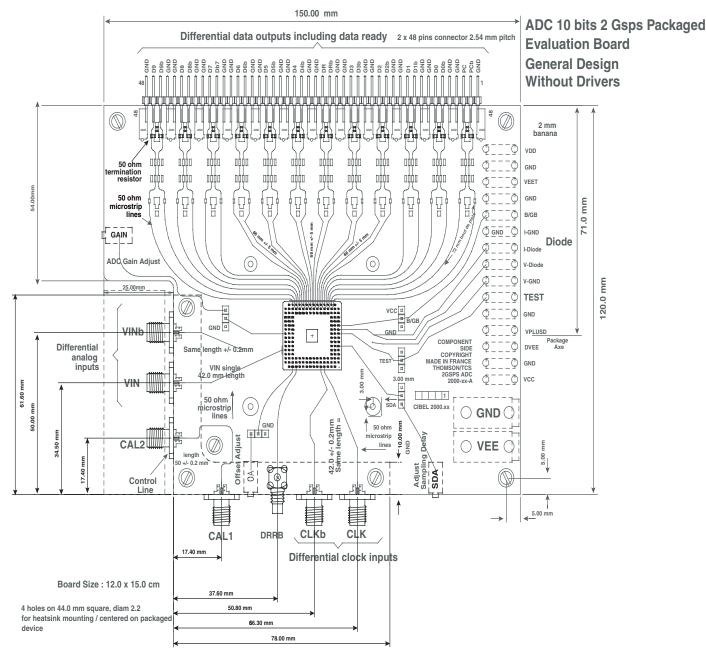
The variation of the delay around its nominal value as a function of the SDA voltage is shown in Figure 56 (simulation result).

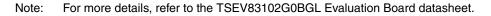




# 14. TSEV83102G0B Evaluation Board

#### Figure 14-1. Schematic Board View





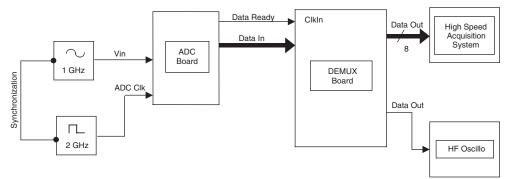
# 15. Applying the TS83102G0B with the TS81102G0 Demultiplexer

The TS83102G0B output data rate can be demultiplexed 4 or 8 times by using the TS81102G0 (8/10-bit parallel channel 2 Gsps 1:4/1:8 demultiplexer).

The ADC's evaluation of static and dynamic performances can be done using the TSEV83102G0BGL ADC evaluation board, coupled with the TS81102G0 DMUX evaluation board and an acquisition system.

The following block diagram shows a typical characterization set-up.

#### Figure 15-1. Characterization Setup



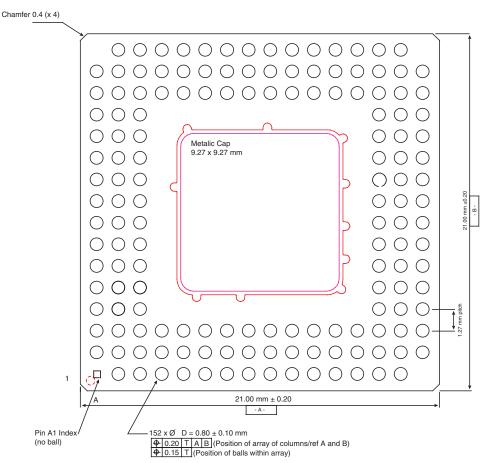
A separate technical specification of the TS81102G0 demultiplexer is available. Refer to this document for further information on the device.

Note: For more information, refer to the "DEMUX and ADCs Application Notes".

# 16. Package Description

# 16.1 Hermetic CBGA 152 Outline Dimensions

Figure 16-1. Mechanical Description Bottom View



- Ceramic body size : 21 x 21 mm
- Ball pitch : 1.27 mm
- Cofired : Al2O3
- Optional: discrete capacitor mounting lands on the top side of the package for extra decoupling.

#### Figure 16-2. Isometric View

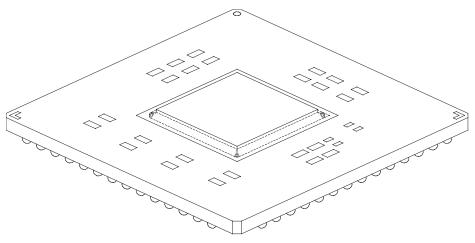
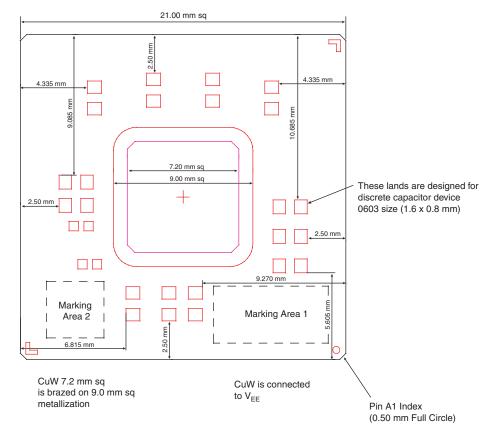
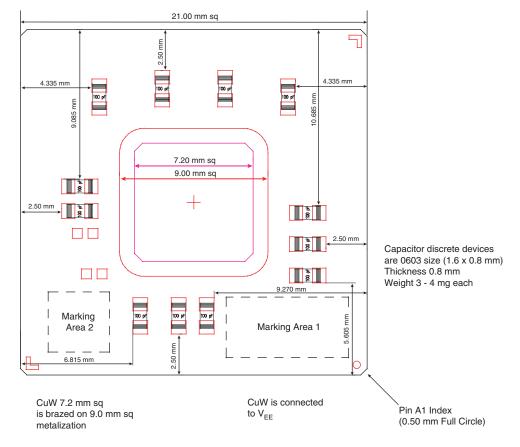


Figure 16-3. Package Top View





#### Figure 16-4. Package Top View with Optional Discrete Capacitors

Note: For additional decoupling of power supplies, extra land capacitors can be used, as shown in Figure 16-4. They are not required if following the evaluation board's decoupling recommendations or if using standard power supply sources (performance results of the device have proven to be equivalent without these capacitors).

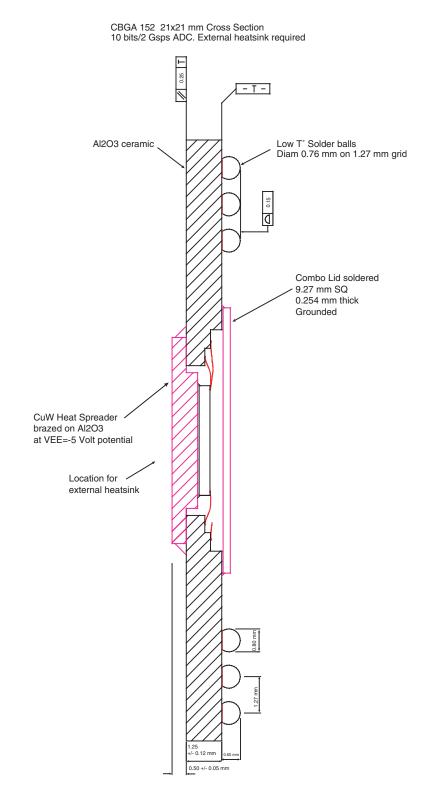


Figure 16-5. Cross Section

# 17. Ordering Information

Part Number	Package	Temperature Range	Screening Level	Comments
TS83102G0BCGL	CBGA 152	"C" 0°C <t<sub>c; T<sub>J</sub> &lt;90°C</t<sub>	Standard product	
TS83102G0BVGL	CBGA 152	"V" -20°C <t<sub>c; T<sub>J</sub> &lt;110°C</t<sub>	Standard product	
TSEV83102G0BGL	CBGA 152	Ambient	Prototype	Evaluation Board (delivered with a heat sink)
JTS83102G0-1V1B	Die	Ambient	Visual inspection	Upon request only (please contact your local sales office)

# **Table of contents**

1	Features 1				
2	Performance 1				
3	Application1				
4	Screening2				
5	Description2				
6	Functional Description				
7	Specification				
	7.1	Absolute Maximum Ratings	3		
	7.2	Recommended Conditions of Use	4		
	7.3	Electrical Operating Characteristics	5		
	7.4	AC Electrical Characteristics at Ambient and Hot Temperatures ( $T_J$ Max)	8		
	7.5	AC Performance at Cold Temperature (T <sub>C</sub> Min)	10		
	7.6Ti	ransient and Switching Performances	11		
8	<b>TS83</b> 1	102G0B Package Description	14		
9	Thern	nal and Moisture Characteristics	17		
9	<b>Thern</b> 9.1	nal and Moisture Characteristics Dissipation by Conduction and Convection			
9			17		
9 10	9.1 9.2	Dissipation by Conduction and Convection	17 18		
-	9.1 9.2 <b>Typic</b>	Dissipation by Conduction and Convection Thermal Dissipation by Conduction Only	17 18 <b> 19</b>		
-	9.1 9.2 <b>Typic</b> 10.1	Dissipation by Conduction and Convection Thermal Dissipation by Conduction Only al Characterization Results	17 18 <b>19</b> 19		
-	9.1 9.2 <b>Typic</b> 10.1 10.2	Dissipation by Conduction and Convection Thermal Dissipation by Conduction Only al Characterization Results Nominal Conditions	17 18 <b>19</b> 19 28		
-	9.1 9.2 <b>Typic</b> 10.1 10.2 10.3	Dissipation by Conduction and Convection Thermal Dissipation by Conduction Only al Characterization Results Nominal Conditions Typical Performance Sensitivity Versus Power Supply and Temperature	17 18 <b>19</b> 19 28 30		
10	9.1 9.2 <b>Typic</b> 10.1 10.2 10.3 <b>Equiv</b>	Dissipation by Conduction and Convection Thermal Dissipation by Conduction Only al Characterization Results Nominal Conditions Typical Performance Sensitivity Versus Power Supply and Temperature Considerations on ENOB: Linearity and Noise Contribution	17 18 <b>19</b> 28 30 <b>31</b>		
10 11	9.1 9.2 10.1 10.2 10.3 Equiv Defini	Dissipation by Conduction and Convection Thermal Dissipation by Conduction Only al Characterization Results Nominal Conditions Typical Performance Sensitivity Versus Power Supply and Temperature Considerations on ENOB: Linearity and Noise Contribution Palent Input/Output Schematics	17 18 19 28 30 31 34		
10 11 12	9.1 9.2 <b>Typic</b> 10.1 10.2 10.3 <b>Equiv</b> Definit	Dissipation by Conduction and Convection Thermal Dissipation by Conduction Only al Characterization Results Al Characterization Results Nominal Conditions Typical Performance Sensitivity Versus Power Supply and Temperature Considerations on ENOB: Linearity and Noise Contribution Palent Input/Output Schematics Tition of Terms	17 18 19 28 30 31 34 36		
10 11 12	9.1 9.2 <b>Typic</b> 10.1 10.2 10.3 <b>Equiv</b> <b>Defini</b> <b>TS83</b> 13.1	Dissipation by Conduction and Convection	17 18 19 28 30 31 34 36 36		
10 11 12	9.1 9.2 <b>Typic</b> 10.1 10.2 10.3 <b>Equiv</b> <b>Defini</b> <b>TS83</b> 13.1 13.2	Dissipation by Conduction and Convection	17 18 19 28 30 31 34 36 36 37		
10 11 12	9.1 9.2 <b>Typic</b> 10.1 10.2 10.3 <b>Equiv</b> <b>Defini</b> <b>TS83</b> 13.1 13.2 13.3	Dissipation by Conduction and Convection	17 18 19 28 30 31 31 36 36 37 39		

17	Ordering Information	55
	16.1 Hermetic CBGA 152 Outline Dimensions	51
16	Package Description	51
15	Applying the TS83102G0B with the TS81102G0 Demultiplexer	49
14	TSEV83102G0B Evaluation Board	49
	13.7 Main Functions of the ADC	44
	13.6 Digital Outputs: Termination and Logic Compatibility	42

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